# MMBFU310LT1G

## **JFET Transistor**

### **N**-Channel

#### Features

• These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DS</sub>	25	Vdc
Gate-Source Voltage	V <sub>GS</sub>	25	Vdc
Gate Current	l <sub>G</sub>	10	mAdc

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

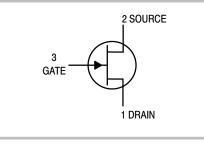
Total Device Dissipation FR- 5 Board (Note 1) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C

1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.



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#### MARKING DIAGRAM



M6C = Device Code M = Date Code\* • = Pb-Free Package

(Note: Microdot may be in either location) \*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MMBFU310LT1G	SOT-23 (Pb-Free)	3000 Tape & Reel

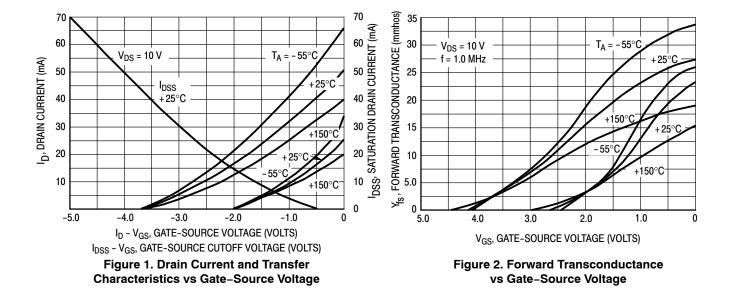
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### MMBFU310LT1G

#### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Gate–Source Breakdown Voltage – ( $I_G = -1.0 \ \mu Adc$ , $V_{DS} = 0$ )	V <sub>(BR)GSS</sub>	-25	-	Vdc
Gate 1 Leakage Current – ( $V_{GS}$ = –15 Vdc, $V_{DS}$ = 0)	I <sub>G1SS</sub>	-	-150	pА
Gate 2 Leakage Current – (V_{GS} = –15 Vdc, V_{DS} = 0, T_A = 125 $^\circ C$ )	I <sub>G2SS</sub>	-	-150	nAdc
Gate Source Cutoff Voltage – ( $V_{DS}$ = 10 Vdc, $I_D$ = 1.0 nAdc)	V <sub>GS(off)</sub>	-2.5	-6.0	Vdc
ON CHARACTERISTICS				
Zero-Gate-Voltage Drain Current - ( $V_{DS}$ = 10 Vdc, $V_{GS}$ = 0)	I <sub>DSS</sub>	24	60	mAdc
Gate-Source Forward Voltage – ( $I_G$ = 10 mAdc, $V_{DS}$ = 0)	V <sub>GS(f)</sub>	-	1.0	Vdc
SMALL-SIGNAL CHARACTERISTICS				
Forward Transfer Admittance – (V_{DS} = 10 Vdc, I_D = 10 mAdc, f = 1.0 kHz)	Y <sub>fs</sub>	10	18	mmhos
Output Admittance – ( $V_{DS}$ = 10 Vdc, $I_D$ = 10 mAdc, f = 1.0 kHz)	y <sub>os</sub>	-	250	μmhos
Input Capacitance – ( $V_{GS}$ = –10 Vdc, $V_{DS}$ = 0 Vdc, f = 1.0 MHz)	C <sub>iss</sub>	-	5.0	pF
Reverse Transfer Capacitance – ( $V_{GS}$ = –10 Vdc, $V_{DS}$ = 0 Vdc, f = 1.0 MHz)	C <sub>rss</sub>	-	2.5	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



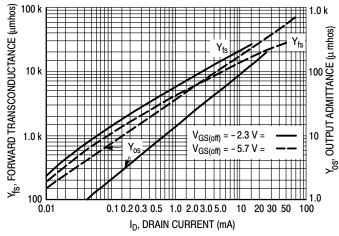
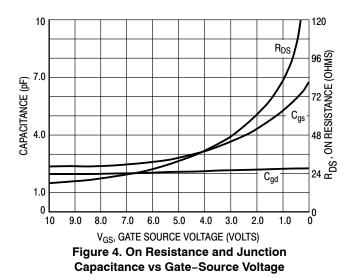


Figure 3. Common–Source Output Admittance and Forward Transconductance vs Drain Current



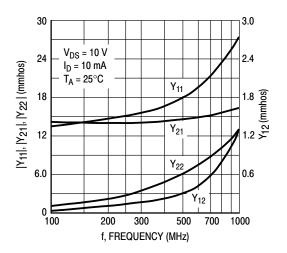


Figure 5. Common–Gate Y Parameter Magnitude vs Frequency

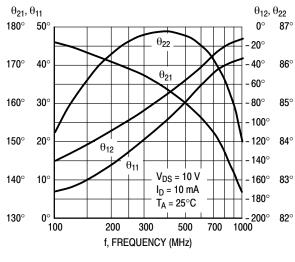


Figure 7. Common–Gate Y Parameter Phase–Angle vs Frequency

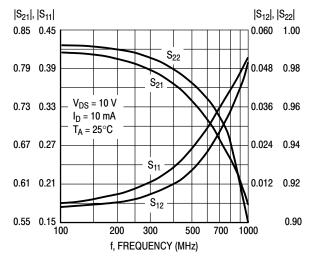


Figure 6. Common–Gate S Parameter Magnitude vs Frequency

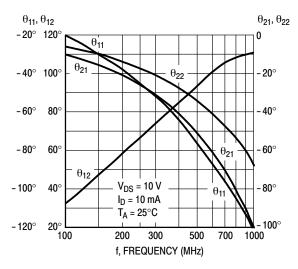


Figure 8. S Parameter Phase-Angle vs Frequency

#### MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

D

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TOP VIEW

SIDE VIEW

Нe

DETAIL A

-3X b

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SCALE 4:1

A\_\_\_\_ ' A1SOT-23 (TO-236) CASE 318 ISSUE AT

0.25

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DETAIL A

END VIEW

DATE 01 MAR 2023

NDTES

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M,1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS		INCHES			
DIM	MIN.	NDM.	MAX.	MIN.	NDM.	MAX.
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
с	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
HE	2.10	2.40	2.64	0.083	0.094	0.104
Т	0*		10*	0*		10*





XXX = Specific Device Code

M = Date Code

= Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



MOUNTING FOOTPRINT

\* For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

#### **STYLES ON PAGE 2**

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## MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

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#### SOT-23 (TO-236) CASE 318 ISSUE AT

#### DATE 01 MAR 2023

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE		
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE	2. CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE	3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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